

PI74LVC3245A

8-Bit Dual Supply Bus Transceiver with 3-State Outputs

Product Features

- 2.7V to 3.6V on A-port and 4.5V to 5.5V on B-port
- TTL Compatible Inputs
- Latch-up performance exceeds 200mA Per JESD78
- ESD protection exceeds JESD22

2000V Human-Body Model (A114-B) 200V Machine Model (A115-A)

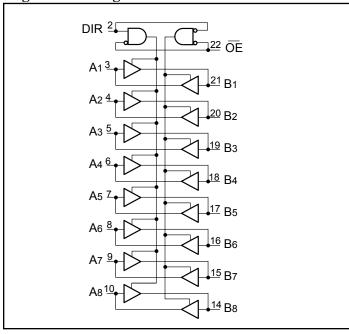
- Industrial Temperature: -40°C to +85°C
- · Available Packages:

24-pin 173-mil wide plastic TSSOP (L)

24-pin 150-mil wide plastic QSOP (Q)

24-pin 300-mil wide plastic SOIC (S)

Logic Block Diagram



Truth Table⁽¹⁾

Inp	outs	Outputs
ŌĒ	DIR	
L	L	Bus B Data to Bus A
L	Н	Bus A Data to Bus B
Н	X	Z (Isolation)

Note

H = High Signal Level
 X = Don't Care or Irrelevant

L = Low Signal Level Z = High Impedance

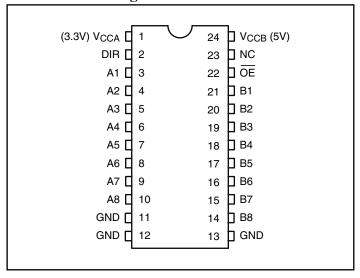
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Product Description

Pericom Semiconductor's PI74LVC series of logic circuits are produced using the Company's advanced submicron CMOS technology, achieving industry leading speed.

The PI74LVC3245A is a non-inverting 8-bit Bidirectional Transceiver that uses two seperate power supply rails. A-port (V_{CCA}) is set to operate at 3.3V and B-port (V_{CCB}) is set to operate at 5V. This allows for translation from a 3.3V to a 5Venvironment and vice-versa. This tranceiver is designed for asynchronous two-way communication between data buses. The direction control input pin (DIR) determines the dataflow from the A bus to the B bus or from the B bus to the A bus. The output enable ($\overline{\rm OE}$) input, when HIGH, disables both A and B ports by placing them in HIGH Z condition.

Product Pin Configuration



Product Pin Description

Pin Name	Description
ŌĒ	3-State Output Enable Inputs (Active LOW)
DIR	Direction Control Input
Ax	Side A Inputs or 3-State Outputs
Bx	Side B Inputs or 3-State Outputs
NC	NO Internal Connect
GND	Ground
V _{CCA} ,V _{CCB}	Power

ADVANCE INFORMATION



PI74LVC3245A 8-Bit Dual Supply Bus Transceiver with 3-State Outputs

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Supply voltage range, V _{CCA} and V _{CCB}	-0.5V to +7V
	$-0.5V$ to $V_{CCA} + 0.5V$
I/O ports (B-port)	0.5V to V _{CCB} +0.5V
Control Pins	$-0.5V$ to $V_{CCA} + 0.5V$
Input clamp current, I _{IK} (V _I <0)	50mA
Output clamp current, I _{OK} (V _O <0)	50mA
Continous Output Current IO	±50mA
Continous Current through each V _{CC} or GND pin	
Package thermal impedance, $\theta_{JA}^{(3)}$: package I	84°C/W
package (2 98°C/W
package S	S 79°C/W
Storage Temperature range, T _{stg}	65°C to 150°C

Notes:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

- 2. This value is limited to 7V maximum.
- 3. The package thermal impedance is calculated in accordance with JESD 51.

P-0.3 08/05/03

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Recommended Operating Conditions⁽⁴⁾

Parameters	Description		V _{CCA}	V _{CCB}	Min.	Тур.	Max.	Units
V _{CCA}	Supply Voltage	•			2.7	3.3	3.6	
V _{CCB}	Supply Voltage				4.5	5	5.5]
V	TT' 1 T 1T 1T 1T 1T	$V_{OB} \le 0.1 v \text{ or}$	2.7V	5.0V	2			1
V_{IHA}	High-Level Input Voltage	$V_{OB} \ge V_{CCB}$ -0.1V	3.6V	5.0V	2]
V	High-Level Input Voltage	$V_{OA} \le 0.1 V$ or	3.3V	4.5V	2]
V_{IHB}	riigh-Level input voitage	$V_{OA} \ge V_{CCA} - 0.1V$	3.3V	5.5V	2			
V	Low Lovel Innet Velters	$V_{OB} \le 0.1 V$ or	2.7V	5.0V			0.8	
V_{ILA}	Low-Level Input Voltage	$V_{OB} \ge V_{CCB} - 0.1V$	3.6V	5.0V			0.8]
3.7	I am I am I I mat Walter a	$V_{OA} \le 0.1 V$ or	3.3V	4.5V			0.8]
$V_{\rm ILB}$	Low-Level Input Voltage	$V_{OA} \ge V_{CCA} - 0.1V$	3.3V	5.5V			0.8	
		$V_{OA} \le 0.1 V$ or	2.7V	4.5V	2			V
$ m V_{IH}$	High-Level Input Voltage (Control Pins)	$\begin{split} V_{OA} &\geq V_{CCA} \text{ -0.1V}, \\ V_{OB} &\leq 0.1 \text{V or} \\ V_{OB} &\geq V_{CCB} \text{ -0.1V} \end{split}$	3.6V	5.5V	2			
		$V_{OA} \le 0.1 V$ or	2.7V	4.5V			0.8	j
$ m V_{IL}$	Low-Level Input Voltage (Control Pins)	$\begin{split} V_{OA} &\geq V_{CCA} \text{-}0.1 \text{V}, \\ V_{OB} &\leq 0.1 \text{V or} \\ V_{OB} &\geq V_{CCB} \text{-}0.1 \text{V} \end{split}$	3.6V	5.5V			0.8	
V _{IA}	Input Voltage				0		V_{CCA}	1
V_{IB}	Input Voltage				0		V _{CCB}	
V _{OA}	Output Voltage				0		V _{CCA}	
V _{OB}	Output Voltage				0		V _{CCB}	
т	High I and Ontone Comment		2.7V	4.5V			-12	
I_{OHA}	High-Level Output Current		3V	4.5V			-24	
I _{OHB}	High-Level Output Current		3V	4.5V			-24	mA
I _{OLA}	Low-Level Output Current		2.7V	4.5V			12	
			3V	4.5V			24	
I _{OLB}	Low-Level Output Current		3V	4.5V			24	1
Δt/Δv	Input transition Rise or Fall Rate						10	ns/v
T _A	Operating Free-Air Temp.				-40		85	°C

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Note: 4. All unused inputs of the device must be held at the associated V_{CC} or GND to ensure proper device operation.



DC Electrical Characteristics (Over the Operating Range, $T_A = -40$ °C +85°C)

Parameters	Description	Test Conditions	V _{CCA}	V _{CCB}	Min.	Тур.	Max.	Units	
		$I_{OH} = -100 \mu A$	3V	4.5V	2.9	3			
	Minimum High Level Output Voltage (Port A)	I 12m A	2.7V	4.5V	2.2	2.55			
$V_{ m OHA}$		$I_{OH} = -12mA$	3V	4.5V	2.4	2.8			
	Output voltage (1 oft 11)	$I_{OH} = -24 \text{mA}$	2.7V	4.5V	2	2.4			
		I()H = -24IIIA	3V	4.5V	2.25	2.7			
$V_{ m OHB}$	Minimum High Level	$I_{OH} = -100 \mu A$	3V	4.5V	4.4	4.5			
VOHB	Output Voltage (Port B)	$I_{OH} = -24 \text{mA}$	3V	4.5V	3.76	4.21		V	
		$I_{OL} = 100 \mu A$	3V	4.5V		0.01	0.1		
Vor	Maximum Low Level	$I_{OL} = 12mA$	2.7V	4.5V		0.09	0.44		
V_{OLA}	Output Voltage (Port A)	I o z = 24m A	2.7V	4.5V		0.18	0.5		
		$I_{OL} = 24mA$	3V	4.5V		0.18	0.44		
Vors	Maximum Low Level	$I_{OL} = 100 \mu A$	3V	4.5V		0.01	0.1		
$V_{ m OLB}$	Output Voltage (Port B)	$I_{OL} = 24mA$	3V	4.5V		0.18	0.44	1	
I_{I}	Maximum Input Leakage Current (Control Inputs)	$V_{\rm I} = V_{\rm CCA}$ or GND	3.6V	5.5V			±1		
I _{OZ} ⁽⁵⁾	Maximum 3-State Output Leakage Current (A or B ports)	$V_{I} = V_{IL} \text{ or } V_{IH}, \overline{OE} = V_{CCA}$ $V_{O} = V_{CCA/B} \text{ or GND}$	3.6V	5.5V			±5	μΑ	
I _{CCA}	Quiescent V _{CCA} Supply Current	B to A, B-Port = V_{CCB} or GND, I_{O} (A port) = 0	3.6V	5.5V			10		
I _{CCB}	Quiescent V _{CCB} Supply Current	A to B, A port = V_{CCA} or GND, I_{O} (B port) = 0	3.6V	5.5V			10		
	I _{CC} per input (A port)		3.6V	5.5V			50		
	I _{CC} per input ($\overline{\rm OE}$)	One input $V_I = V_{CCA} - 0.6V$, other inputs = V_{CCA} or GND, DIR = V_{CCA}	3.6V	5.5V			50	uA	
$\Delta I_{CC}^{(6)}$	I _{CC} per input (DIR)	$V_{I} = V_{CCA} - 0.6V, \text{ other}$ inputs = V_{CCA} or GND, \overline{OE} = GND	3.6V	5.5V			50		
	I _{CC} per input (B Port)	One Input $V_I = V_{CCB} - 2.1V$, other inputs = V_{CCB} or GND, $\overline{OE} = GND$ and DIR = GND	3.6V	5.5V		0.7	1.5	mA	

Notes:

5. For I/O ports, the parameter I_{OZ} includes the input leakage current.

6. This is the increase in supply current for each input that is at one of the specified voltage levels, rather than 0V or the associated V_{CC}.

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Capacitance $(T_A = 25^{\circ}C)$

Param- eters	Description	Test Conditions		Тур.	Units
C_{IN}	Control Input Capacitance	$V_I = V_{CCA}$ or GND, $V_{CCA} = Open$, $V_{CCB} = Open$		2.8	
C _{I/O}	Input/Output Capacitance (A or B port)	$V_{I/O} = V_{CCA/B}$ or GN	9	pF	
C	Power Dissipation	Outputs Enabled $V_{CCA} = 3.3V, V_{CCB} = 5V$		22	
C_{PD}	Capacitance (7)	Outputs Disabled	$C_L = 0pF, f = 10MHz$	2.2	

Notes:

AC Electrical Characteristics (Over Operating Range, $T_A = -40$ °C to +85°C)

			$V_{CCA} = 2.7V \text{ to } 3.6V$	$V_{CCA} = 2.7V \text{ to } 3.6V, V_{CCB} = 5V \pm 0.5V$		
Parameters	From (Input)	To (Output)	$C_L = 50 pF$	$R_L = 500\Omega$	Units	
			Min.	Max.		
$t_{ m PHL}$	A	В	1.0	6.3		
$t_{\rm PLH}$	A	Ð	1.0	6.0		
$t_{ m PHL}$	В	A	1.0	5.7		
$t_{\rm PLH}$	D	Α	1.0	6.0		
t_{PZL}	ŌĒ	A	1.0	7.8		
t_{PZH}		A	1.0	7.5		
t _{PZL}	ŌĒ	В	1.0	7.8	ns	
t _{PZH}	OL	Ð	1.0	7.6		
$t_{\rm PLZ}$	ŌĒ	A	1.0	7.0		
t_{PHZ}		A	1.0	7.5		
$t_{\rm PLZ}$	ŌĒ	В	1.0	7.0		
t_{PHZ}		D	E D	1.0	7.3	
t _{SK(O)}	Output-to-	Output Skew ⁽⁸⁾		1.5		

Note:

8. Skew between any two outputs of the same device, switching in the same direction. Parameter guaranteed by design.

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C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle, C_{PD} is related to I_{CCD} dynamic operating current by the expression: I_{CCD} = (C_{PD})(V_{CC})(f_{IN}) +(I_{CC} static)



Power- Up Considerations

To avoid excessive supply current, bus contention or oscillation during power-up, the following guidelines should be followed:

- 1. Connect ground first before any supply voltage is applied.
- 2. Power up V_{CCA}, which is the control side of the device.
- 3. Ramp \overline{OE} ahead of or with V_{CCA} to help prevent bus contention
- 4. Ramp DIR with V_{CCA} if DIR high is needed (A bus to B bus). Otherwise keep DIR Low.

PARAMETER MEASUREMENT INFORMATION FOR A TO B PORT V_{CCA} =2.7V TO 3.6V and V_{CCB} = 5V ± 0.5V

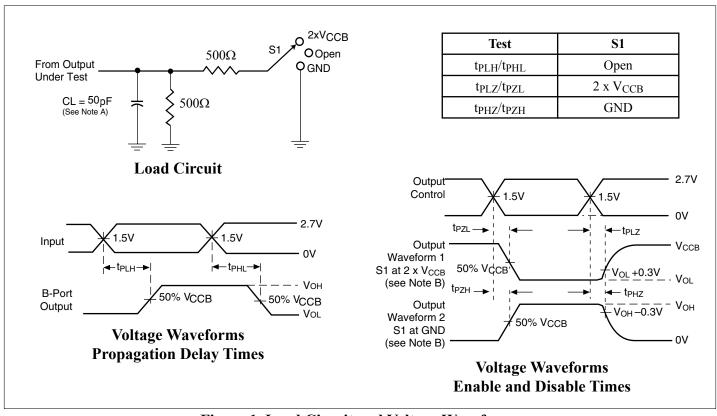


Figure 1. Load Circuit and Voltage Waveforms

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Notes:

- A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input impulses are supplied by generators having the following characteristics: $PRR \le 10 \text{ MHz}$, $Z_O = 50\Omega$, $t_R \le 2.5 \text{ns}$, $t_F \le 2.5 \text{ns}$.
- D. The outputs are measured one at a time with one transition per measurement.



PARAMETER MEASUREMENT INFORMATION FOR B TO A PORT V_{CCA} =2.7V TO 3.6V and V_{CCB} = 5V ± 0.5V

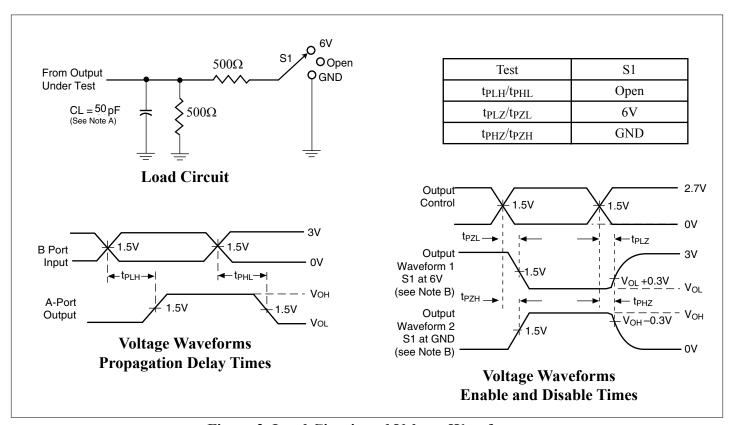


Figure 2. Load Circuit and Voltage Waveforms

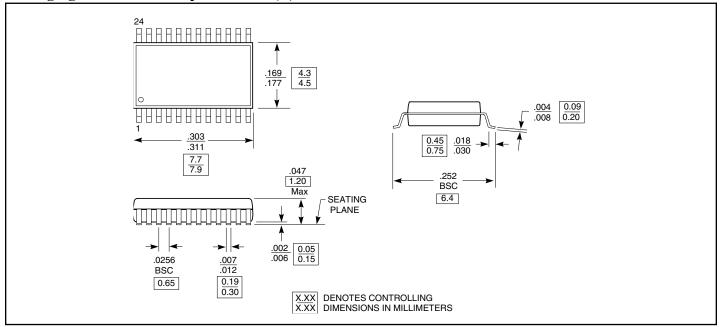
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Notes:

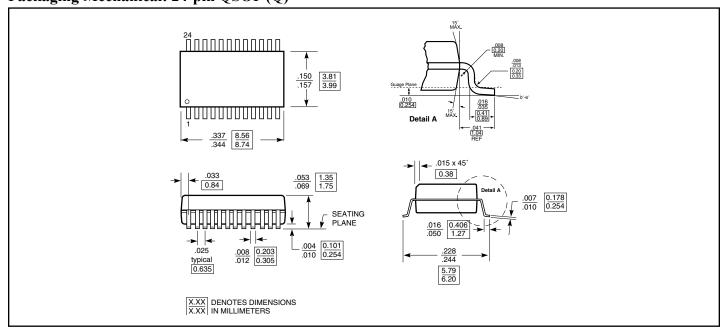
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- C. All input impulses are supplied by generators having the following characteristics: $PRR \le 10 \text{ MHz}$, $Z_O = 50\Omega$, $t_R \le 2.5 \text{ns}$, $t_F \le 2.5 \text{ns}$.
- D. The outputs are measured one at a time with one transition per measurement.



Packaging Mechanical: 24-pin TSSOP (L)



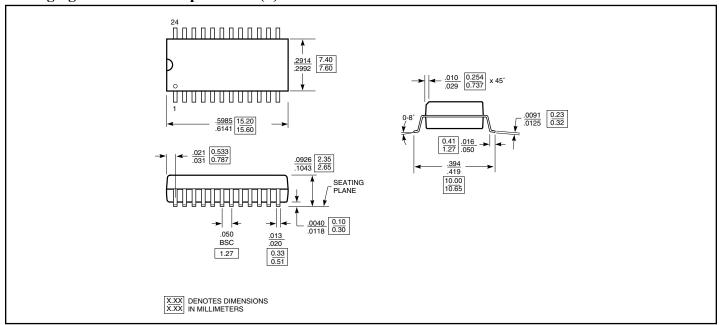
Packaging Mechanical: 24-pin QSOP (Q)



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Packaging Mechanical: 24-pin SOIC (S)



Ordering Information

Ordering Code	Package Code	Package Type
PI74LVC3245AL	L	24-pin, 173-mil wide plastic TSSOP
PI74LVC3245AQ	Q	24-pin, 150-mil wide plastic QSOP
PI74LVC3245AS	S	24-pin, 300-mil wide plastic SOIC

Notes:

1. Thermal characteristics can be found on the company web site at http://www.pericom.com/packaging/mechanicals.php

Pericom Semiconductor Corporation

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